
	<h2>SIR164DP-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIR164DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 50A PPAK SO-8</p> <p>Datenblätter:  SIR164DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 173361 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIR164DP-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 50A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	173361 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	5.2W (Ta), 69W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	50A (Tc)
Rds On (Max) @ Id, Vgs	2.5 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	123nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3950pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































SIR164DP-T1-GE3 ist neu im Original, Suche SIR164DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIR164DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIR164DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIR158DP-T1-RE3 Electro-Films (EF1) / Vishay MOSFET N-CH 30V 60A POWERPAKSO-8</p>	 <p>SIR158DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 60A PPAK SO-8</p>	 <p>SIR164DP-T1-GE3 Vishay / Spectrol MOSFET N-CH 30V 50A PPAK SO-8</p>	 <p>SIR164DP-T1-E3 VISHAY SIR164DP-T1-E3 VISHAY</p>
 <p>SIR164ADP-T1-GE3 QQ2850920 SIR164ADP-T1-GE3 QQ2850920</p>	 <p>SIR166DP V SIR166DP V</p>	 <p>SIR164DP SI SIR164DP SI</p>	 <p>SIR164DY-T1-GE3 VISHAY SIR164DY-T1-GE3 VISHAY</p>

heiße Teile

Mehr

 SIR-312STT32	 SIR-34ST3F	 SIR-563ST3F	 SIR-563ST3FM	 SIR-563ST3FN
 SIR-563ST3FP	 SIR-563ST3FX	 SIR-56SB3F	 SIR-56ST3F	 SIR-59SSTA47
 SIR11-21C/TR8	 SIR15-21C/TR8	 SIR158DP	 SIR158DP-T1-E3	 SIR158DP-T1-GE3
 SIR158DP-T1-GE3	 SIR164ADP-T1-GE3	 SIR164DP	 SIR164DP-T1-E3	 SIR164DP-T1-GE3
 SIR166DP	 SIR166DP-T1-E3	 SIR166DP-T1-GE3	 SIR166DP-T1-GE3	 SIR168DP
 SIR168DP-T1-GE3	 SIR168DP-T1-GE3	 SIR172ADP-T1-GE3	 SIR172ADP-T1-GE3	 SIR172DP
 SIR172DP-T1-E3	 SIR172DP-T1-GE3	 SIR172DP-T1-GE3	 SIR330DP-T1-GE3	 SIR330DP-T1-GE3
 SIR402DP-T1-GE3	 SIR402DP-T1-GE3	 SIR403EDP-T1-GE3	 SIR403EDP-T1-GE3	 SIR404DP
 SIR404DP-T1-E3	 SIR404DP-T1-GE3	 SIR404DP-T1-GE3	 SIR406DP	 SIR406DP-T1-E3
 SIR406DP-T1-GE3	 SIR406DP-T1-GE3	 SIR406DP-T1-GE3-S	 SIR408DP-T1-GE3	 SIR408DP-T1-GE3

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited